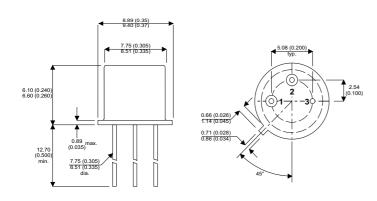




#### **MECHANICAL DATA**

Dimensions in mm (inches)

# **PNP SILICON TRANSISTORS**



#### **DESCRIPTION**

The 2N5679 and 2N5680 are silicon expitaxial planar PNP transistors in jedec TO-39 metal case intended for use as drivers for high power transistors in general purpose, amplifier and switching circuit

The complementary NPN types are the 2N5681 and 2N5682 respectively

**TO-39** 

Pin 1 - Emitter Pin 2 - Base Pin 3 - Collector

### **ABSOLUTE MAXIMUM RATINGS**

T <sub>CASE</sub> = 25°c unless otherwise stated		2N5679	2N5680	
$V_{CBO}$	Collector – Base Voltage	-100V	-120V	
$V_{CEO}$	Collector – Emitter Voltage (I <sub>B</sub> = 0)	-100V	-120V	
$V_{EBO}$	Emitter – Base Voltage (I <sub>C</sub> = 0)	-4V		
I <sub>C</sub>	Continuous Collector Current	-1A		
I <sub>B</sub>	Base Current	-0.5A		
$P_{tot}$	Total Dissipation at T <sub>case</sub> ≤ 25°C	10W		
	T <sub>amb</sub> ≤ 25°C	1W		
T <sub>stg</sub>	Operating and Storage Temperature Range	−65 to +200°C		
Tj	Junction temperature	200°C		

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## THERMAL DATA

R <sub>thj-case</sub>	Thermal Resistance Junction-case	Max	17.5	°C/W
R <sub>thj-amb</sub>	Thermal Resistance Junction-ambient	Max	175	°C/W

# **ELECTRICAL CHARACTERISTICS** (T<sub>case</sub> = 25°C unless otherwise stated)

	Parameter	Test Conditions		Min.	Тур.	Max.	Unit		
		I <sub>E</sub> = 0							
I <sub>CBO</sub>	Collector Cut Off Current	for 2N5679	$V_{CB} = -100V$			-1	μA		
		for 2N5680	$V_{CB} = -120V$			-1			
ı	Collector Cut Off Current	V <sub>BE</sub> = 1.5							
I <sub>CEV</sub>		for 2N5679	$V_{CE} = -100V$			-1	μΑ		
		for 2N5680	$V_{CE} = -120V$			-1			
		T <sub>case</sub> = 150°0	С						
		for 2N5679	$V_{CE} = -100V$			-1	mA		
		for 2n5680	$V_{CE} = -120V$			-1			
		$I_B = 0$							
I <sub>CEO</sub>	Collector Cut Off Current	for 2N5679	$V_{CE} = -70V$			-10			
		for 2N5680	$V_{CE} = -80V$			-10	μA		
I <sub>EBO</sub>	Emitter Cut Off Current	$I_C = 0$	V <sub>EB</sub> = -4V			-1			
	Collector Emitter Sustaining Voltage	$I_B = 0$	$I_C = -10mA$				V		
V <sub>CEO(sus)*</sub>		for 2N5679		-100					
0_0(000)		for 2N5680		-120					
	Collector Emitter Saturation Voltage	$I_{C} = -250 \text{mA}$	$I_B = -25 \text{mA}$			-0.6			
V <sub>CE(sat)*</sub>		$I_{C} = -500 \text{mA}$	$I_B = -50 \text{mA}$			-1			
,		I <sub>C</sub> = -1A	$I_{B} = -200 \text{mA}$			-2			
V <sub>BE*</sub>	Base Emitter Voltage	$I_{C} = -250 \text{mA}$	V <sub>CE</sub> = -2V			-1			
h <sub>FE*</sub>	DC Current Gain	$I_{C} = -250 \text{mA}$	V <sub>CE</sub> = -2V	40		150			
		$I_C = -1A$	$V_{CE} = -2V$	5					
f <sub>T</sub>	Transistion Frequency	$I_{C} = -100 \text{mA}$	V <sub>CE</sub> = -10V	20			MHz		
		f = 10MHz		30					
C <sub>CBO</sub>	Collector Base Capacitance	I <sub>E</sub> = 0	V <sub>CB</sub> = -20V			50			
		f = 1MHz				50	pF		
L	Constitution of Comment Code	$I_{C} = -0.2A$	$V_{CE} = -1.5V$	40					
h <sub>fe</sub>	Small Signal Current Gain	f = 1KHz							

<sup>\*</sup> Pulse test  $t_p = 300\mu s$  ,  $\delta < 2\%$ 

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